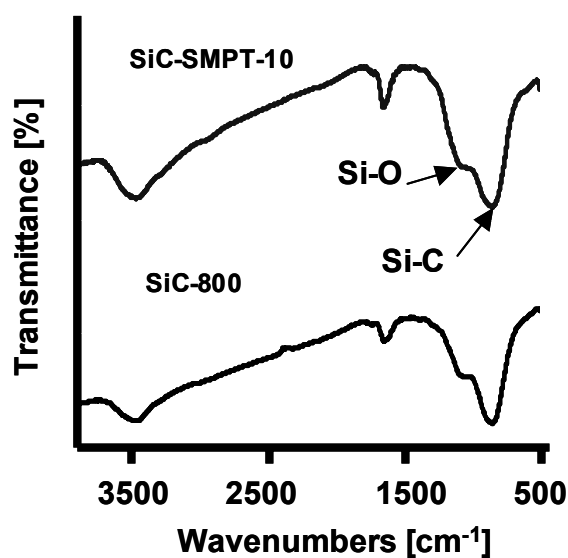


Supporting Information:

Ordered mesoporous silicon carbide (OM-SiC) via polymer precursor nanocasting

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IR spectra of the mesoporous silicon carbide materials SiC-800 and SiC-SMPT-10. The Si-C bonds were detected at 830cm⁻¹ together with a minor presence Si-O species at 1040cm⁻¹.